

Surface Mount Transient Voltage Suppressors

SMBJ5.0A thru SMBJ188A

General Semiconductor



DO-214AA (SMB J-Bend)

FEATURES

- Low profile package
- Ideal for automated placement
- Glass passivated chip junction
- Available in uni-directional and bi-directional
- 600 W peak pulse power capability with a 10/1000 μ s waveform, repetitive rate (duty cycle): 0.01 %
- Excellent clamping capability
- Very fast response time
- Low incremental surge resistance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: For definitions of compliance



RoHS
COMPLIANT

PRIMARY CHARACTERISTICS

V_{BR} (bi-directional)	6.4 V to 231 V
V_{BR} (uni-directional)	6.4 V to 231 V
V_{WM}	5.0 V to 188 V
P_{PPM}	600 W
I_{FSD} (uni-directional only)	100 A
T_J max.	150 °C
Polarity	Uni-directional, bi-directional
Package	DO-214AA (SMBJ)

TYPICAL APPLICATIONS

Use in sensitive electronics protection against voltage transients induced by inductive load switching and lighting on ICs, MOSFET, signal lines of sensor units for consumer, computer, industrial, and telecommunication.

MECHANICAL DATA

Case: DO-214AA (SMBJ)

Molding compound meets UL 94 V-0 flammability rating
Base P/N-E3 - RoHS-compliant, commercial grade
Base P/NHE3 - RoHS-compliant, AEC-Q101 qualified

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 2 whisker test, HE3 suffix meets JESD 201 class 2 whisker test

Polarity: For uni-directional types the band denotes cathode end, no marking on bi-directional types

DEVICES FOR BI-DIRECTION APPLICATIONS

For bi-directional devices use CA suffix (e.g. SMBJ10CA).

Electrical characteristics apply in both directions.

MAXIMUM RATINGS ($T_A = 25$ °C unless otherwise noted)

PARAMETER	SYMBOL	VALUE	UNIT
Peak pulse power dissipation with a 10/1000 μ s waveform ⁽¹⁾⁽²⁾ (fig. 1)	P_{PPM}	600	W
Peak pulse current with a 10/1000 μ s waveform ⁽¹⁾	I_{PPM}	See next table	A
Peak forward surge current 8.3 ms single half sine-wave uni-directional only ⁽²⁾	I_{FSD}	100	A
Operating junction and storage temperature range	T_J , T_{STG}	- 55 to + 150	°C

Notes

⁽¹⁾ Non-repetitive current pulse, per fig. 3 and derated above $T_A = 25$ °C per fig. 2.

⁽²⁾ Mounted on 0.2" x 0.2" (5.0 mm x 5.0 mm) copper pads to each terminal

SMBJ5.0A thru SMBJ188A

General Semiconductor

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

DEVICE TYPE 型号	DEVICE MARKING CODE 设备编码		BREAKDOWN VOLTAGE VBR AT IT ⁽¹⁾ (V) 崩溃电压		TEST CURRENT IT (mA) 测试电流	STAND-OFF VOLTAGE VWM (V) 对峰值电压	MAXIMUM REVERSE LEAKAGE AT VWM ID (μA) ⁽³⁾ 最大反向漏电	MAXIMUM PEAK PULSE SURGE CURRENT IPPm (A) ⁽²⁾ 最大峰值脉冲电流	MAXIMUM CLAMPING VOLTAGE AT IPPm VC (V) 最大箝位电压
	UNI	BI	MIN.	MAX.					
(+)SMBJ5.0A ⁽⁵⁾	KE	KE	6.40	7.07	10	5.0	800	65.2	9.2
(+)SMBJ6.0A	KG	KG	6.67	7.37	10	6.0	800	58.3	10.3
(+)SMBJ6.5A	KK	AK	7.22	7.98	10	6.5	500	53.6	11.2
(+)SMBJ7.0A	KM	KM	7.78	8.60	10	7.0	200	50.0	12.0
(+)SMBJ7.5A	KP	AP	8.33	9.21	1.0	7.5	100	46.5	12.9
(+)SMBJ8.0A	KR	AR	8.89	9.83	1.0	8.0	50	44.1	13.6
(+)SMBJ8.5A	KT	AT	9.44	10.4	1.0	8.5	20	41.7	14.4
(+)SMBJ9.0A	KV	AV	10.0	11.1	1.0	9.0	10	39.0	15.4
(+)SMBJ10A	KX	AX	11.1	12.3	1.0	10	5.0	35.3	17.0
(+)SMBJ11A	KZ	KZ	12.2	13.5	1.0	11	5.0	33.0	18.2
(+)SMBJ12A	LE	BE	13.3	14.7	1.0	12	5.0	30.2	19.9
(+)SMBJ13A	LG	LG	14.4	15.9	1.0	13	1.0	27.9	21.5
(+)SMBJ14A	LK	BK	15.6	17.2	1.0	14	1.0	25.9	23.2
(+)SMBJ15A	LM	BM	16.7	18.5	1.0	15	1.0	24.6	24.4
(+)SMBJ16A	LP	LM	17.8	19.7	1.0	16	1.0	23.1	26.0
(+)SMBJ17A	LR	LR	18.9	20.9	1.0	17	1.0	21.7	27.6
(+)SMBJ18A	LT	BT	20.0	22.1	1.0	18	1.0	20.5	29.2
(+)SMBJ20A	LV	LV	22.2	24.5	1.0	20	1.0	18.5	32.4
(+)SMBJ22A	LX	BX	24.4	26.9	1.0	22	1.0	16.9	35.5
(+)SMBJ24A	LZ	BZ	26.7	29.5	1.0	24	1.0	15.4	38.9
(+)SMBJ26A	ME	CE	28.9	31.9	1.0	26	1.0	14.3	42.1
(+)SMBJ28A	MG	MG	31.1	34.4	1.0	28	1.0	13.2	45.4
(+)SMBJ30A	MK	CK	33.3	36.8	1.0	30	1.0	12.4	48.4
(+)SMBJ33A	MM	CM	36.7	40.6	1.0	33	1.0	11.3	53.3
(+)SMBJ36A	MP	CP	40.0	44.2	1.0	36	1.0	10.3	58.1
(+)SMBJ40A	MR	CR	44.4	49.1	1.0	40	1.0	9.3	64.5
(+)SMBJ43A	MT	CT	47.8	52.8	1.0	43	1.0	8.6	69.4
(+)SMBJ45A	MV	MV	50.0	55.3	1.0	45	1.0	8.3	72.7
(+)SMBJ48A	MX	MX	53.3	58.9	1.0	48	1.0	7.8	77.4
(+)SMBJ51A	MZ	MZ	56.7	62.7	1.0	51	1.0	7.3	82.4
(+)SMBJ54A	NE	NE	60.0	66.3	1.0	54	1.0	6.9	87.1
(+)SMBJ58A	NG	NG	64.4	71.2	1.0	58	1.0	6.4	93.6
(+)SMBJ60A	NK	NK	66.7	73.7	1.0	60	1.0	6.2	96.8
(+)SMBJ64A	NM	NM	71.1	78.6	1.0	64	1.0	5.8	103
(+)SMBJ70A	NP	NP	77.8	86.0	1.0	70	1.0	5.3	113
(+)SMBJ75A	NR	NR	83.3	92.1	1.0	75	1.0	5.0	121
(+)SMBJ78A	NT	NT	86.7	95.8	1.0	78	1.0	4.8	126
(+)SMBJ85A	NV	NV	94.4	104	1.0	85	1.0	4.4	137
(+)SMBJ90A	NX	NX	100	111	1.0	90	1.0	4.1	146
(+)SMBJ100A	NZ	NZ	111	123	1.0	100	1.0	3.7	162
(+)SMBJ110A	PE	PE	122	135	1.0	110	1.0	3.4	177
(+)SMBJ120A	PG	PG	133	147	1.0	120	1.0	3.1	193
(+)SMBJ130A	PK	PK	144	159	1.0	130	1.0	2.9	209
(+)SMBJ150A	PM	PM	167	185	1.0	150	1.0	2.5	243
(+)SMBJ160A	PP	PP	178	197	1.0	160	1.0	2.3	259
(+)SMBJ170A	PR	PR	189	209	1.0	170	1.0	2.2	275
SMBJ188A	PS	PS	209	231	1.0	188	1.0	2.0	328

Notes

- (1) Pulse test: $t_p \leq 50$ ms
- (2) Surge current waveform per fig. 3 and derate per fig. 2
- (3) For bi-directional types having V_{WM} of 10 V and less, the I_D limit is doubled
- (4) All terms and symbols are consistent with ANSI/IEEE C62.35
- (5) For the bi-directional SMBJ5.0CA, the maximum V_{BR} is 7.25 V
- (6) $V_F = 3.5$ V max. at $I_F = 50$ A (uni-directional only)
- (+) Underwriters laboratory recognition for the classification of protectors (QVGQ2) under the UL standard for safety 497B and file number E136766 for both uni-directional and bi-directional devices

SMBJ5.0A thru SMBJ188A

General Semiconductor

THERMAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	VALUE	UNIT
Typical thermal resistance, junction to ambient ⁽¹⁾	$R_{\theta JA}$	100	$^\circ\text{C}/\text{W}$
Typical thermal resistance, junction to lead	$R_{\theta JL}$	20	

Note

⁽¹⁾ Mounted on minimum recommended pad layout

ORDERING INFORMATION (Example)

PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
SMBJ5.0A-E3/52	0.096	52	750	7" diameter plastic tape and reel
SMBJ5.0A-E3/5B	0.096	5B	3200	13" diameter plastic tape and reel
SMBJ5.0AHE3/52 ⁽¹⁾	0.096	52	750	7" diameter plastic tape and reel
SMBJ5.0AHE3/5B ⁽¹⁾	0.096	5B	3200	13" diameter plastic tape and reel

Note

⁽¹⁾ AEC-Q101 qualified

RATINGS AND CHARACTERISTICS CURVES ($T_A = 25^\circ\text{C}$ unless otherwise noted)

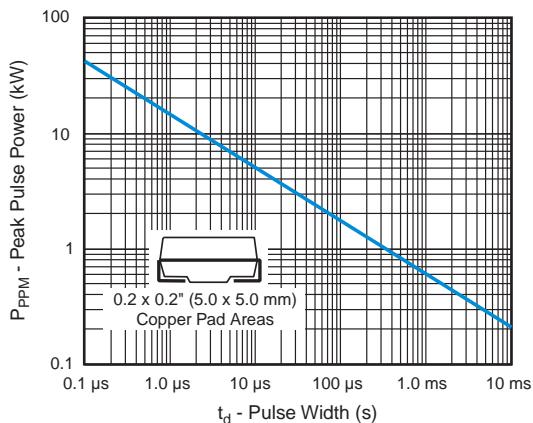


Fig. 1 - Peak Pulse Power Rating Curve

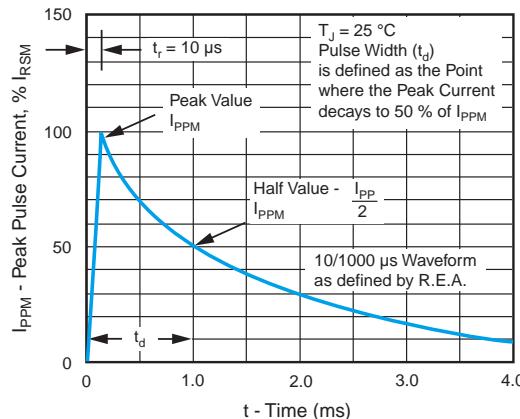


Fig. 3 - Pulse Waveform

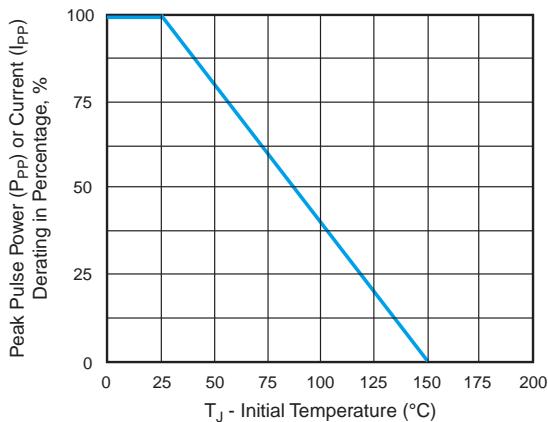


Fig. 2 - Pulse Power or Current vs. Initial Junction Temperature

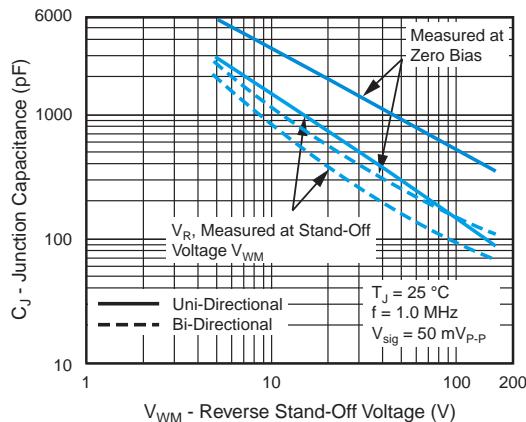


Fig. 4 - Typical Junction Capacitance

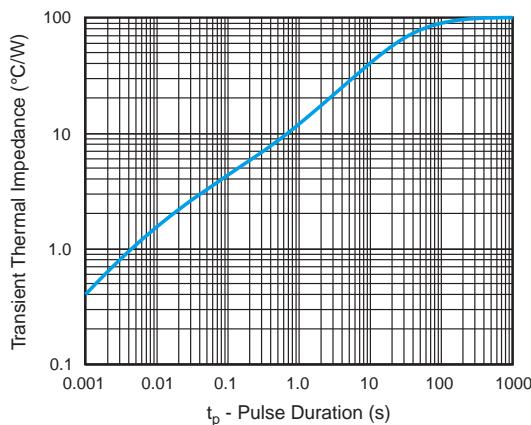


Fig. 5 - Typical Transient Thermal Impedance

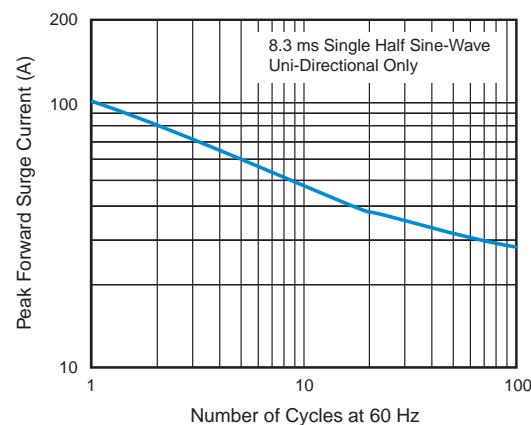
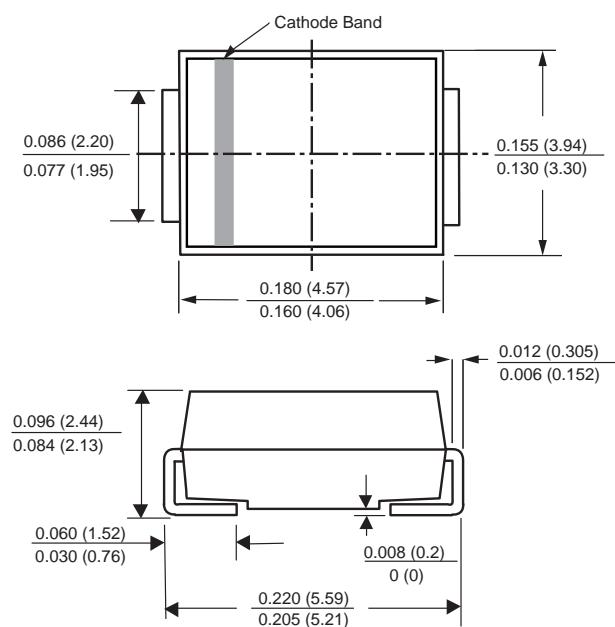


Fig. 6 - Maximum Non-Repetitive Peak Forward Surge Current

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

DO-214AA (SMB-J-Bend)



Mounting Pad Layout

